

IXTP4N70X2M Datasheet



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DiGi Electronics Part Number IXTP4N70X2M-DG

Manufacturer IXYS

Manufacturer Product Number IXTP4N70X2M

Description MOSFET N-CH 700V 4A TO220

Detailed Description N-Channel 700 V 4A (Tc) 30W (Tc) Through Hole TO

-220 Isolated Tab



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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
IXTP4N70X2M	IXYS
Series:	Product Status:
Ultra X2	Active
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
700 V	4A (Tc)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ Id, Vgs:
10V	850m0hm @ 2A, 10V
Vgs(th) (Max) @ Id:	Gate Charge (Qg) (Max) @ Vgs:
4.5V @ 250μA	11.8 nC @ 10 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±30V	386 pF @ 25 V
FET Feature:	Power Dissipation (Max):
	30W (Tc)
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Through Hole
Supplier Device Package:	Package / Case:
TO-220 Isolated Tab	TO-220-3 Full Pack, Isolated Tab
Base Product Number:	
IXTP4	

Environmental & Export classification

8541.29.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	Not Applicable
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



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